

## INCHANGE SEMICONDUCTOR

## **Isc N-Channel MOSFET Transistor**

# **FDA59N30**

### • FEATURES

- With To-3P package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

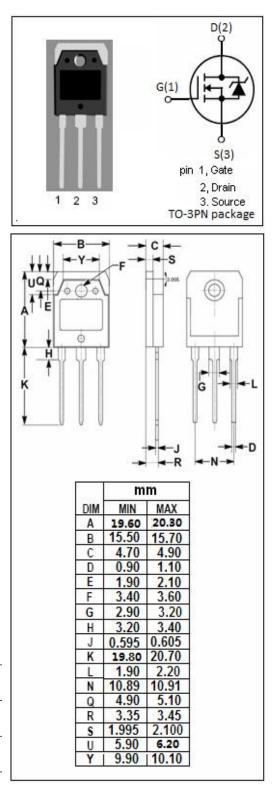
Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	300	V				
V <sub>GSS</sub>	Gate-Source Voltage	±30	A V				
ID	Drain Current-ContinuousTc=25℃ Tc=100℃	59 35	A				
I <sub>DM</sub>	Drain Current-Single Pulsed	236	A				
PD	Total Dissipation @T <sub>C</sub> =25°C	500	W				
T <sub>ch</sub>	Max. Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.25	°C/W	
Rth(ch-a)	h(ch-a) Channel-to-ambient thermal resistance		°C <b>/W</b>	

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## ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}C$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	300			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	3.0		5.0	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =29.5A		47	56	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =300V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> =240V; V <sub>GS</sub> = 0V;Tj=125℃			1 10	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =59A, V <sub>GS</sub> = 0V			1.4	v

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